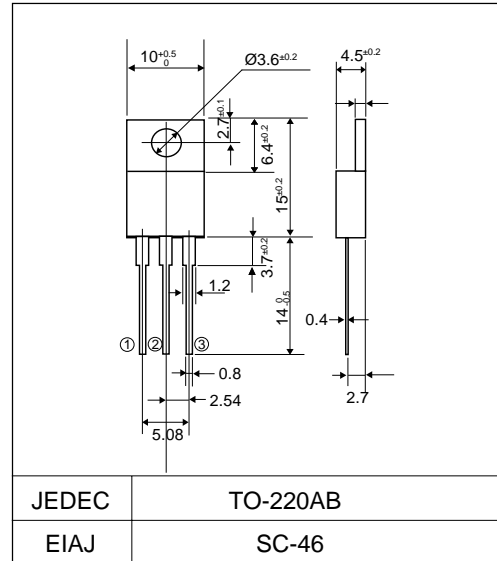


ESAC82-006 (10A)

(60V / 10A)

SCHOTTKY BARRIER DIODE

Outline drawings, mm



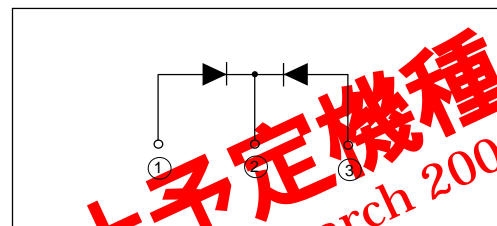
Features

- Low V_F
- Super high speed switching
- High reliability by planer design

Applications

- High speed power switching

Connection diagram



Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}		60	V
Non-repetitive peak reverse voltage	V_{RSM}	$t_w=500\mu s$, duty=1/40	60	V
Average output current	I_o	Square wave, duty=1/2 $T_c=123^\circ C$	10*	A
Surge current	I_{FSM}	Sine wave 10ms	80	A
Operating junction temperature	T_j		-40 to +150	$^\circ C$
Storage temperature	T_{stg}		-40 to +150	$^\circ C$

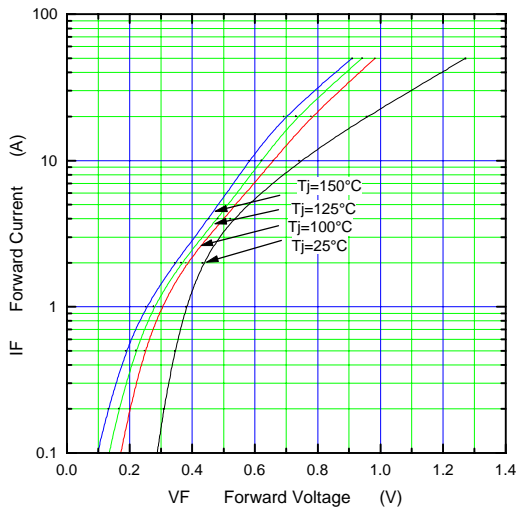
* Average forward current of centertap full wave connection

- Electrical characteristics ($T_a=25^\circ C$ Unless otherwise specified)

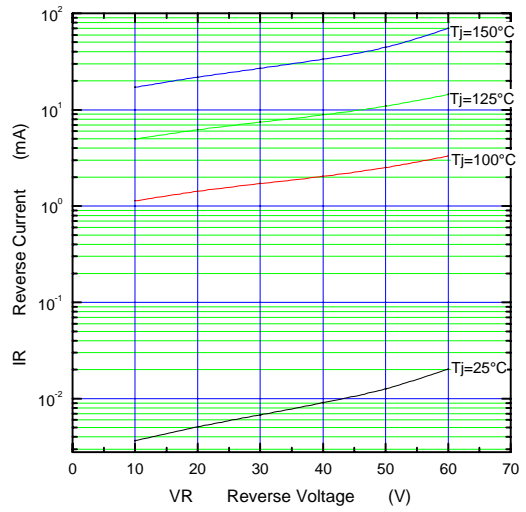
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_{FM}	$I_{FM}=4.0A$	0.58	V
Reverse current	I_{RRM}	$V_R=V_{RRM}$	5	mA
Thermal resistance	$R_{th(j-c)}$	Junction to case	3.0	$^\circ C/W$

Characteristics

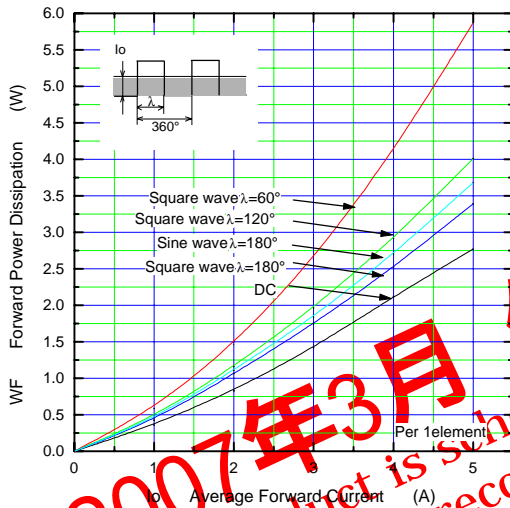
Forward Characteristic (typ.)



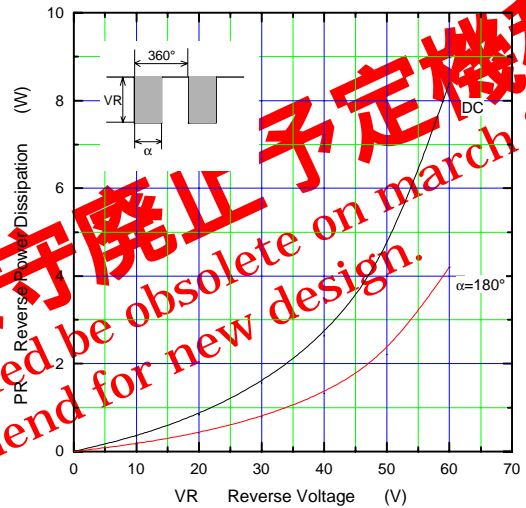
Reverse Characteristic (typ.)



Forward Power Dissipation

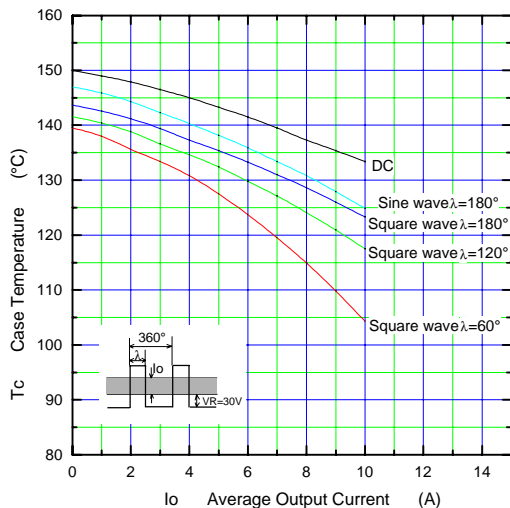


Reverse Power Dissipation

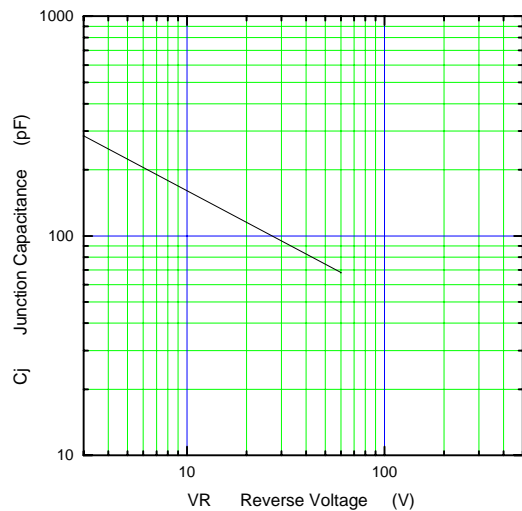


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This product is scheduled to be obsolete on march 2007.
Not recommend for new design.

Current Derating (Io-Tc)

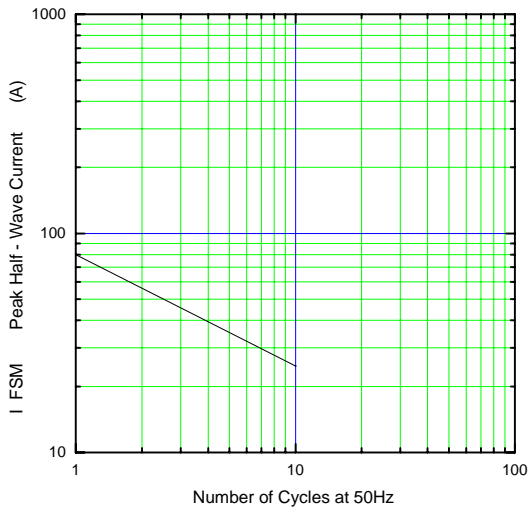


Junction Capacitance Characteristic (typ.)

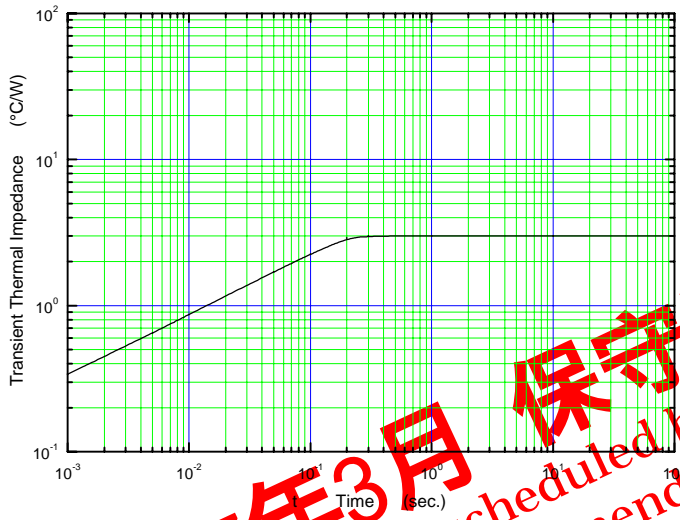


λ : Conduction angle of forward current for each rectifier element
Io : Output current of center-tap full wave connection

Surge Capability



Transient Thermal Impedance



2007年3月 保守廃止予定機種
This product is scheduled to be obsolete on march 2007.
Not recommend for new design.